# Interoffice Correspondence

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Subject: Report of hot argon cycle purge experiment at PVD chamber work center

## A faster way to receive UHV in a PVD chamber

#### I. Introduction

In order to further reduce the chamber test cycle time, the PVD chamber work center has been working with an outside company, Galiso-Nuvac, since July of 1995 to introduce a hot gas purge technique, developed by Galiso-Nuvac and labeled "HGS (Hot Gas Sweep)", into Applied Materials at Austin.

At earlier stages of the experiment, an argon recirculation machine was used with a PVD chamber to speed up the bakeout process. The results did not show a noticeable reduction in bakeout time. The probable reason is the gas delivery setup that was available at the time did not meet Nuvac's requirement for UHP Ar gas.

Galiso-Nuvac proposed a hot argon sweep method to achieve UHV in a PVD chamber. The first positive result came on November 15, which showed that PVD chamber bakeout time could be reduced by more than 50% in comparison to the presently specified procedure. After two more chamber tests to see how far this technique could be taken with PVD, the work center decided to purchase the experimental equipment including software.

In order to test the reliability of the technique and equipment, six widebody PVD chambers with almost identical configurations have been rigorously tested during the last two weeks before Christmas shutdown. A clean, very well baked LeyBold Inficon RGA was also used to monitor chamber contamination. The test results show that hot argon cycle purge on the PVD chamber is a repeatable technique. It will reduce chamber bakeout time by at least 20 - 25 hours.

This report starts from a baseline - present PVD chamber vacuum qualifying process, then briefly describes the hot argon cycle purge experimental process. A detailed result of all test chambers and typical pump down curves, together with typical RGA scans will be given. Some discussion will follow.

#### II. Baseline - Present PVD Chamber Vacuum Qualifying Process

- 1. Chamber Configuration
- A virgin PVD chamber (Standard, Widebody or Watercooled)
- A process kit
- A source with Cu or Al backing plate
- 2. Pumping System
- CTI 8T Cryogenic pump
- The cryo-shield is installed to reduce heat and radiation into the cryopump
- A pair of standoffs are installed to increase pumping speed during vacuum test
- A LeyBold leak detector is used as a roughing pump
- 3. Bakeout Elements
- Two bakeout lamps with 500 W each
- Center heater (Size 5", 6" or 8")
- 4. Main Bakeout Process
- Purge the chamber with 20 psi dry nitrogen for 1 2 hours
- Roughing down to about 100 millitorr, then open the gate valve
- Pump down to less than 3.0E-6 torr, turn on the bakeout lamps
- After 32 hours of lamp bakeout, turn on the heater for four more hour's bakeout (lamps stay on)
- Turn off both lamps and heater after the 32 + 4 hours of bakeout, cool down without cooling water
- 5. Qualifying Specification (at chamber test work center)
- Base pressure: 6.0E-9 torr
- Rate of rise: 1.5E-6 torr/2min.

III. Hot Argon Cycle Purge Experiment

The layout of the hot argon cycle purge experiment is shown in Fig. 1. Compared with normal PVD chamber test, the main differences are:

- (1) A dry pump is directly connected to the roughing line of PVD chamber
- (2) An ultra-pure argon gas line is connected to the chamber through heater and/or bypass gas line
- (3) A controller (HGS-1) is used to control the argon line valve, roughing valve and gate valve
- (4) Computer software is used as an interface between the PVD chamber and the controller, automatically opening or closing valves and controlling the argon cycle purge time

The purity of argon gas is very important for this technique. The critical parameter is the water partial pressure in the argon gas. In this experiment, the commercially available ultra-pure liquid argon contains less than one ppm (part per million) of water. An argon purifier is used in the line to further reduce the water partial pressure to a level of less than 10 ppb (part per billion).

A 1000 torr baratron in addition to the 0.1 torr baratron, which was originally used with the PVD system is used to monitor the pressure in the chamber during argon purge. Two rod-type thermocouples are also used to monitor the external temperature of the chamber body.

Before turning on the bakeout lamps, the chamber is filled with the ultrapure argon and pumped down to the 50 millitorr for three times (Cold purge). Then the chamber is pumped down to high E-7 torr and the bakeout lamps and heater are turned on. Then the chamber is pumped by the dry pump instead of the cryogenic pump. The argon valve is periodically opened and closed for about 20 cycles. During this period of about three hours, the heater is ramped up from 100 °C to 400 °C (Ramp purge). A hot argon purge of up to 10 cycles follows. The dry pump and the cryogenic pump are alternately used to pump the chamber. During the cryo-pumping period, the ion gauge can be turned on and the pressure reading and a rate of rise measurement can be used as indicators to show if the chamber is ready to cool down (Hot purge).

When the chamber is ready to cool down, the argon gas is turned off and then the gate valve is opened. All heating elements are turned off at this point except the ion gauge baking jacket. The Neslab cooling water can be used to cool the heater and the source as long as the pressure in the chamber is below 1.0E-6 torr. The cooling water will reduce the cool down time by 5 - 10 hours. TempScan software is also used to record the pumpdown curve through the ion gauge reading.

#### IV. Results

1. "Feasability Test" period: Nov. 14 - Nov. 30, 1995

Equipment owner: Galiso-Nuvac (One-chamber controller)

Quantity of test chamber: Three

Brief information:

Type	Cryo-Shield	Standoff	Bakeout-time	Qual. or Fail
(1) W/B, 8	" On	On	14 hours	6.0E-9 torr
(2) W/B, 8	" Off	Off	8 hours	6.0E-9 torr
(3) W/B, 8	" On	Off	4.5 hours	Failed
Detailed in	nformation is	shown on	the Table 1.	

2. "Repeatability Test" period: Dec. 5 - Dec. 17, 1995

Equipment owner: AMET chamber (One-chamber controller)

Quantity of test chamber: Six

Brief information:

Type Cry	o-Shield	Standoff	Bakeout-time	Qual. or Fail
(1) W/B, 8"	On	$\mathbf{On}$	12.5 hours	6.0E-9 torr
(2) W/B, 8"	On	$\mathbf{On}$	13 hours	3.0E-9 torr
(3) W/B, 8"	On	On	10.5 hours	Wafer Lift Leak
(4) W/B, 8"	On	On	11 hours	Gate Valve Leak
(5) W/B, 8"	On	On	14 hours	3.0E-9 torr
(6) W/B, 8"	$\mathbf{On}$	On	11 hours	2.0E-9 torr
Detailed info	rmation	is shown or	Table 2	

3. "Process Verification" period: Dec. 21.96 - Feb. 96

Equipment owner: AMET chamber (Three-chamber controller)

Quantity of test chamber: Thirty (proposed)

Brief information:

Type	Cryo	-Shield	Standoff	Bakeout-time	Qual. or Fail
(1) W/B,	8"	On	On	11 hours	5.0E-9 torr
(2) W/B,	8"	On	On	11 hours	2.0E-9 torr
(3) W/B,	8"	On	On	11 hours	Ion gauge defect

Detailed information will be provided after the experiment finished

#### V. Discussion

1. Experiments performed at the PVD chamber work center have shown, after leaving out three chambers with unrelated part failures, that the hot argon cycle purge process is faster and is a repeatable way to obtain ultrahigh vacuum in a PVD chamber. Starting from the present baseline, without any configuration change in the chamber, it will reduce bakeout time by at least 20 hours per chamber. If the cooling water is used to cool the heater and the source, at least 5 more cooling hours will also be reduced. With this new bakeout technique, the capacity of the chamber work center will be potentially increase by about 85% without additional test controllers and test

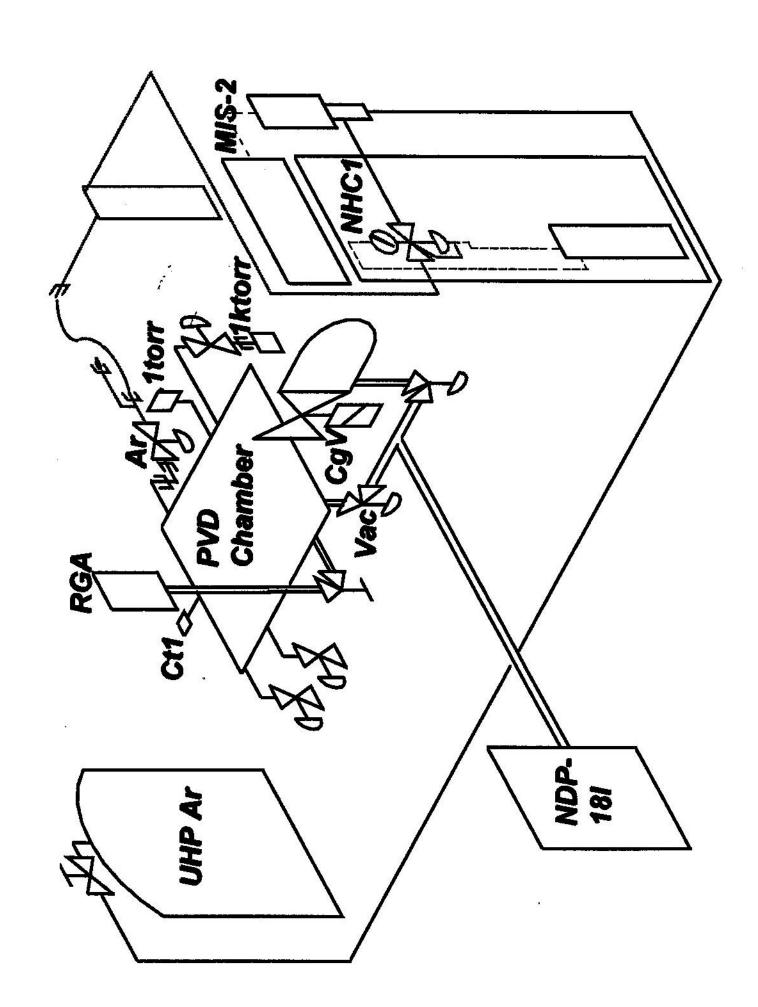
ports (see the attached chamber test capacity analysis). The ultra-pure argon and dry pump used in this technique allow an ultra-high vacuum chamber, like the PVD chamber, to be pumped in a much higher pressure region so that the water vapor and other contaminants can be more efficiently removed from the vacuum chamber. A detailed theoretical explanation will be given shortly in a separate paper.

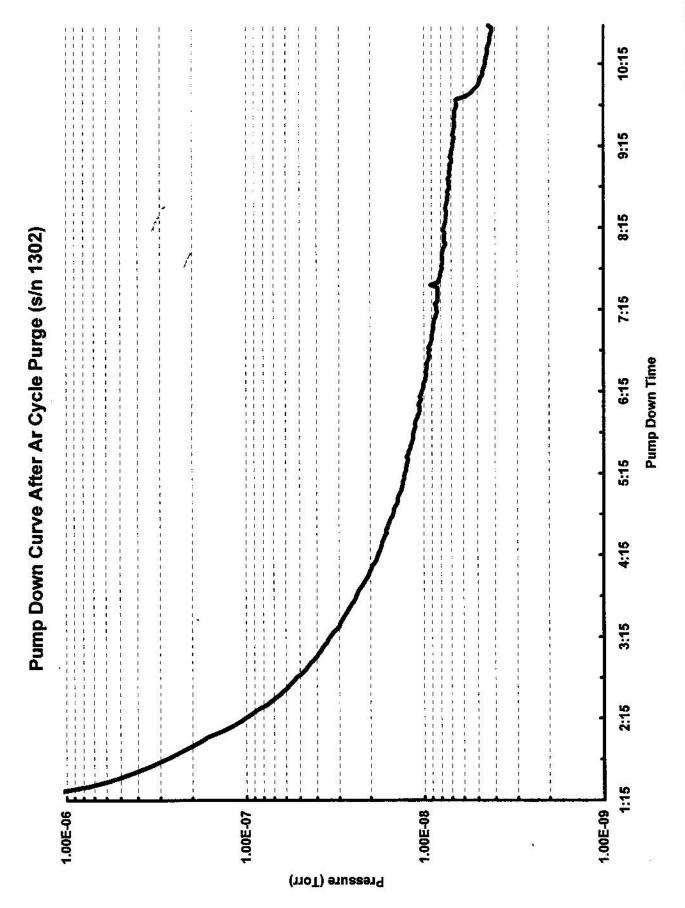
- 2. There are three failed chambers which involved defective parts, including a leak at the wafer lift and gate valve and damage of ion gauge filament. Once the defective parts had been identified and replaced, all three chambers were easily qualified after 1 2 hours of rebaking. These results show that water and other contamination have been efficiently removed from these chambers during the hot argon cycle purge. The failure reason of the only chamber which did not involve a defective part was probably due to bakeout time that was too short (4.5 hours). This chamber was also tested using a hot argon purge of the cryopump while the gate valve was opened. The failure may suggest that hot argon purge of the cryopump is not a good idea, and it has been eliminated from all following tests.
- 3. During the "Repeatability Test" period, a well-baked RGA head has been used to monitor all six test chambers. The RGA scan data shows that this new bakeout technique does not cause any additional contamination. Typical RGA data including background and after-bakeout scan have been included along with this report.
- 4. When the chamber work center purchased the test equipment, request of automation of argon purge process and modification of the single-chamber controller into multi-chamber controller have been discussed. Now the three-chamber controller has been tested for the first three chambers, and it operates satisfactory. The software for automation of the process has been tested several times. In order to solve an occasional lock-up problem of the interface computer and ensure a safe work environment, the work center is working with Galiso-Nuvac to debug the software and to install an uninterruptable power supply (UPS) into the interface computer. Concurrently, technologist training in this new technique is also scheduled for the chamber test module.
- 5. Further Testing: The work center is planning to test a variety of chambers, currently being tested in the chamber test module, utilizing the hot argon cycle purge technique in the near future. This will involve a 101% chamber which is not equipped with a heater, a PVD chamber which is equipped with a heater but not equipped with the heater argon line, a watercooled chamber which is equipped with a large cryopump elbow and a HTHU heater which needs a much longer bakeout time, a preclean chamber and a clamped-degas chamber. The resulting bakeout time and cooldown pressure and ROR for

each of these chambers needs to be determined during the testing. The possible impact of this technique to chamber qualification will also be investigated. The experiment results will be provided as soon as possible.

### Appendix

- 1. Figure 1: Layout of the hot argon cycle purge experiment
- 2. Figure 2: Typical pump down curve after hot argon cycle purge
- 3. Table 1: Test results of first three "Feasability Test" chambers
- 4. Table 2: Test results of the six "Repeatability Test" chambers
- 5. Figure 3: RGA background scan (LeyBold Head 4530)
- 6. Figure 4: RGA scan of the qualified chamber S/N 1262 using hot argon cycle purge (LeyBold Head 4530)
- 7. PVD chamber test/capacity analysis





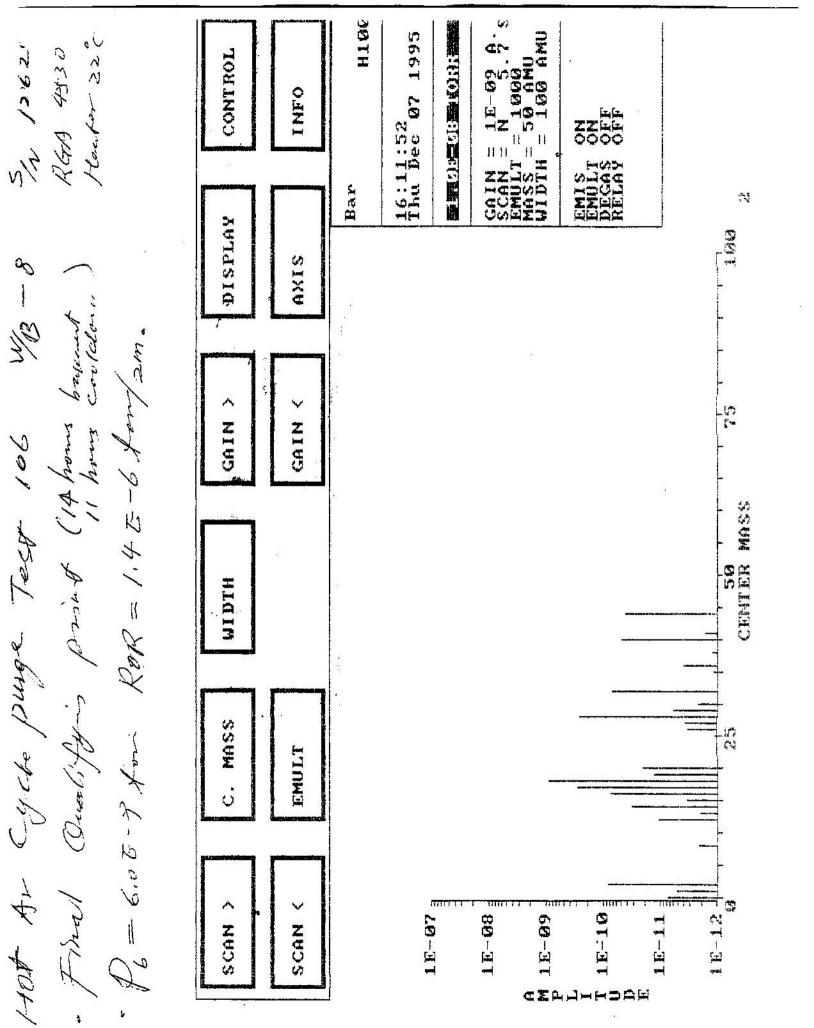
	List of ultra	-pure argo	List of ultra-pure argon cycle purge test	etest							
ò.	Date	Chamber	Chamber Source &	Heater	Cryo-Shield Standoff	Standoff	Bakeout Tim Cool Tim	Cool Tim	Total Tim	Total Tim QF Pressure	Rate of Rise
			Process Kit								
	Nov. 14-16 1089 W//B Yes	1089 W/B	Yes	 	ő	5	14 hours	15 hours	29 hours	6.0E-9 torr	7.9E-7 torr/2m.**
	Hot argon pu	irge the ch	Hot argon purge the chamber only, no chill water	chill wat	er during cooldown	lown					
	Test personr	el: Chuck	Test personnel: Chuck Granci, Carl Hoover(Nuv	oover(Nu	vac) Joe Zhor	u, Zbigniew	ac) Joe Zhou, Zbigniew Golinski(AMET				
334									,		
2	Nov. 17-19 1282 W/B Yes	1282 W/B	Yes	 &	JJO	Off	8 hours	4 hours	12 hours	6.0E-9 torr	N/A
	Hot argón pu	irge the chi	amber only, ch	ill,water f	low through th	e target and	Hot argon purge the chamber only, chill,water flow through the target and heater during cooldown	cooldown			
_	Re-QF		Yes	<u>.</u> 8	Ou	ပ်	2 hours	20 hours	22 hours	6.0E-9 torr	9.3E-7 torr/2m.
	Test person	nel: Chuck	Test personnel: Chuck Granci, Carl Hoover(Nuv	oover(Nu	vac) Steve Da	asso, Zbigni	ac) Steve Dasso, Zbignlew Golinski (AMET)	MET)			
	Nov 28-30 1250 W/B Yes	1250 W/B	Yes	ōc	ő	#0	4.5 hours	N/A	N/A	Failed 2 QE-8 forr	N/A
T	Hot argon pu	rge both c	Hot argon purge both chamber and cryopump w	\ dwndo\.	while the gate	valve opene	hile the gate valve opened, chill water colldown	olldown			
	Test personr	el: Chuck	Granci, Carl H	oover(Nu	vac) Joe Zhoi	J, Zbigniew	Test personnel: Chuck Granci, Carl Hoover(Nuvac) Joe Zhou, Zbigniew Golinski(AMET				
	2000, 50	8									
res	ent AMET p	rocedure	Present AMET procedure of chamber bakeout	akeont						Specification	
			Yes	2",6",8"	uO.	o	36 hours	15 - 18	51 - 54	6.0E-9 torr	1.5E-6 torr/2m.
				or 101			(32 + 4)		- Alleria		

Purge Reliability Test	on Cycle Purge Reliability Te	n Cycle Purge Reliability T
Purge R	on Cycle Purge Re	Hot Argon Cycle Purge Re
	on Cycle	Hot Argon Cycle

and a make make a part	a i digo inchide	3001				
Test Number	7-	2	3	4	5	9
Test Date	6/12 - 7/12	8/12 - 9/12	10/12 - 11/12	12/12 - 13/12	14/12 - 15/12	16/12 - 17/12
Chamber Type - Heater Wide Body - 8"	Wide Body - 8"	Wide Body - 8"	Wide Body - 8"	Wide Body - 8"	Wide Body - 8"	Wide Body - 8"
System Number, S/N	3685-4, 1262	3687-2, 1302	3688-2, 1288	3690-1, 1290	3692-4, 1225	3696-3, 1346
Backing Plate	Cu	AI	Cu	AI	Al	A
Process Kit	Yes	Yes (G-12)	Yes	Yes (G-12)	Yes	Yes
Shuttler Arm ?	No	No	ON	No	Yes	No
With Cryoshield?	Yes	Yes	Sə	Yes -<	Yes	Yes
With Standoff?	Yes	Yes	Yes	Yes	Yes	Yes
Bakeout Time (hours)	12.5	13	10.5	11	14	11
Cooling With Water?	Yes **	Yes **	Yes	Yes	Yes	Yes
Time to 6.0E-9 torr	11.5	8	8	N/A	8.5	5
Time to Qualifying	11.5	10	N/A	N/A	10	8.5
Base Pressure *	6.0E-9 torr	3.0E-9 torr	3.0E-9 torr	1.0E-7 torr	3.0E-9 torr	2.0E-9 torr
Rate of Rise	1.4E-6 torr/2m.	1.4E-6 torr/2m. 3.0E-6 torr/2m.	3.0E-6 torr/2m.	1.7E-6 torr/2m.	1.5E-6 torr/2m. 1.3E-6 torr/2m	1.3E-6 torr/2m.
Qulified ?	QF	QF	Failed	Failed	QF	QF
Start to Finish Time	25	24	N/A	N/A	25	20
Software Through ?	Yes	Yes	No	No	Yes	No
Auto or Semi-auto	Semi-Manuat	Semi-Auto	Auto	Auto	Auto	Auto
If Fail, What's Reason	N/A	N/A	Wafer lift leak	GV leak	N/A	N/A
Re-Bakeout Time	N/A	N/A	1.5 Hours	1 Hour	N/A	N/A s
Final Pressure	N/A	N/A	2.0E-9 torr	6.0E-9 torr	N/A	N/A
Test Personnel	Joe Z.	Joe Z.	Joe Z.	Joe Z.	Joe Z.	Joe Z.
	Zbigniew G.	Lindsey(galiso)	Lindsey(galiso)	Lindsey(galiso)	Zbigniew G.	Zbigniew G.
		Steve D.	Zbigniew G.	Zbigniew G.		
		Zbigniew G.				

\*\* Cooling facility failure noticed during cooldown \* Stable Ion Gauge for all six test chambers

1E-09 A.S.7 S. 1000 AMU 10 Helpines 節を買りになるに乗り入りに最高 1995 INFO EXIT 11:14:10 Fri Dec 61 3h 136 2 1181 4, 1 DISPLAY 100 AXIS Het Ar Grade Junge Tosk -17 19-8" GAIN GAIN CEMTER MASS PRINT REA Book grad PLZ4) = 1,05 - 9 for 1E-10 1E-67 1E-08 1E-09



# PVD CHAMBER TEST CAPACITY ANALYSIS/NUVAC Q1 (91 SYSTEMS)

VARIABLES	Current	Nuvac						
SET-UP	0.5	0.5						
LEAK CHECK	0.5	0.5		DD'L HRS				24
COOL CRYO	4	4	Α	DD'L HRS	FOR TC w	rafer		24
INSTL PROC KIT	0.5	0.5						
N2 PURGE	2	0						
PUMP DOWN	2	0						
BAKE OUT	32	14						
<b>B/O W-HEATER</b>	4	0						
COOL DOWN	18	8						
FINAL TEST	0.5	0.5						
MAT ISSUES	8	8						
MISC OTHER	Ø	0						
1st PASS HRS	72	36						
2nd PASS HRS	24	24						
						4.4	01	
	SYS	СНМ	WKS	QTY	%	1st PASS	2nd PASS	TOT HRS
SYSTEM	QTY	PER	QTR	WK	YĽD	HRS	HRS	REQ
ENDURA	86	3.8	13	25.14	90%	1810	60	1870
CENTURA	5	2.3	13	0.88	90%	64	2	66
NSO	39	2.3 1	13	3.00	90%	216	7	223
TC wafer test	22	1	13	1.65	90%	40	4	44
MISC OTHER	13	1	13	1.00	90%	<del>4</del> 0 72	2	1200000
MISCUINER		Is PER W			90%	12	-	74
			chamber=	29.02 78.47				2277
	weign	iggu i ii a.n		70.47				
					007/			
ENDURA	86	3.8	13	25.14	90%	905	60	965
CENTURA	5	2.3	13	0.88	90%	32	2	34
NSO	39	1	13	3.00	90%	108	7	115
TC wafer test	22	1	13	1.65	90%	66	7	72
MISC OTHER	13	1	13	1.00	90%	36	2 _	38
		As PER W	CONTRACTOR CONTRACTOR	29.02				1225
	Weigh	ited Hrs./	chamber=	42.21				
Number of Nuvac	ports:	3	n <del>160</del>					
CONTROLLERS			4	4	4	4	4	4
PORTS			19	20	21	22	23	24
DAYS/WK			6.5	6.5	6.5	6.5	6.5	6.5
HRS/DAY			21	21	21	21	21	21
HRS/WK PER POR	T		137	137	137	137	137	137
			10.500		920 <u>-</u> 12			
Standard ports			16	17	18	19	23	24
Nuvac ports			3	3	3	3	3	3
Max. number of Ch.	hab (Q14)	V	28	30	31	33	40	42
	ANN INSTITUTE							74
Max, number of Ch.	200							10
Max. number of Ch. Total max. Number	./wk (Nuv	ac)	10	10	10	10	10	
Max. number of Ch. Total max. Number Utilization	./wk (Nuv	ac)						10 51 <b>56%</b>